

UNISONIC TECHNOLOGIES CO., LTD

UTT1D5N10

Preliminary

Power MOSFET

1.5A, 100V N-CHANNEL LOGIC LEVEL ENHANCEMENT **MODE FIELD EFFECT** TRANSISTOR

DESCRIPTION

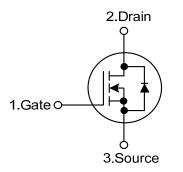
The UTC UTT1D5N10 is an N-channel MOSFET, it uses UTC's advanced technology to provide the customers with high switch speed and low gate charge.

3 SOT-23-3 (JEDEC TO-236)

FEATURES

- * R_{DS(ON)} ≤ 290 mΩ @ V_{GS}=10V, I_D=0.75A
- $R_{DS(ON)} \le 300 \text{ m}\Omega @ V_{GS}=4.5V, I_{D}=0.7A$
- * High switch speed
- * Low gate charge

SYMBOL



ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Deaking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTT1D5N10L-AE2-R UTT1D5N10G-AE2-R		SOT-23-3	G	S	D	Tape Reel	

S: Source Note: Pin Assignment: G: Gate D: Drain

UTT1D5N10G-AE2-R T T (1)Packing Type	(1) R: Tape Reel
(2)Package Type	(2) AE2: SOT-23-3
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free
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S126 L: Lead Free G: Halogen Free	A PANING



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ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise noted)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V _{DSS}	100	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current	Continuous T _A =25°C	- I _D -	1.5	А
	(Note 1) T _A =70°C		1.2	А
	Pulsed (Note 2)	I _{DM}	5	А
Single Pulsed Avalanche Energy (Note 4)		E _{AS}	8	mJ
Power Dissipation (Note 1)	T _A =25°C	Р	1.25	W
	T _A =70°C	PD	0.8	W
Junction Temperature		TJ	-55 ~ +150	°C
Storage Temperature Range		T _{STG}	-55 ~ +150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient (Note 1)	θ _{JA}	100	°C/W

ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS		·				
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250µA, V _{GS} =0V	100			V
Drain-Source Leakage Current	I _{DSS}	V _{DS} =80V, V _{GS} =0V			1	μA
Forward	I _{GSS}	V _{GS} =+20V, V _{DS} =0V			+100	nA
Gate-Source Leakage Current Reverse		V _{GS} =-20V, V _{DS} =0V			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	V _{GS(TH)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.7	2.5	V
		V _{GS} =10V, I _D =0.75A		290		mΩ
Static Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =0.7A		300		mΩ
DYNAMIC PARAMETERS (Note 3)						
Input Capacitance	CISS			350		pF
Output Capacitance	Coss	V _{GS} =0V, V _{DS} =25V, f=1.0MHz		28		pF
Reverse Transfer Capacitance	C _{RSS}			23		pF
SWITCHING PARAMETERS (Note 3)						
Total Gate Charge	Q_{G}			75		nC
Gate to Source Charge	Q_{GS}	V _{GS} =10V, V _{DS} =50V, I _D =1.3A		3		nC
Gate to Drain Charge	Q_{GD}	-I _G =100μΑ		2.2		nC
Turn-ON Delay Time	t _{D(ON)}			26		ns
Rise Time	t _R	V_{DD} =30V, I _D =0.5A, R _{GEN} =25 Ω ,		15		ns
Turn-OFF Delay Time	t _{D(OFF)}	V _{GS} =10V		170		ns
Fall-Time	t _F			54		ns
SOURCE- DRAIN DIODE RATINGS AND						
Drain-Source Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V		0.8	1.2	V
Notes: 1. Surface Mounted on FR4 Board	t ≤ 10sec.	1				
2. Pulse Test:Pulse Width≤300us,	Duty Cycle≤ 2%		~			
3. Guaranteed by design, not subje	ect to production	n testing.	1.			
4. Starting T _J =25°C, L=0.5mH, V _{DD}	=50V.(See Figu	ure1)				
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		TEL IST OL				
	X	A PALINS				
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UIC www.unisonic.com.tw		I _S =1A, V _{GS} =0V			QW-R209-	057.a

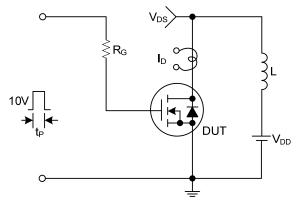
- 2. Pulse Test:Pulse Width≤300us, Duty Cycle≤ 2%.
- 3. Guaranteed by design, not subject to production testing.
- 4. Starting TJ=25°C, L=0.5mH, VDD=50V.(See Figure1)

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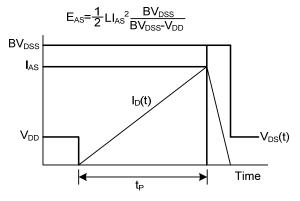
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Preliminary

TEST CIRCUITS AND WAVEFORMS



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

Figure 1.

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